

Legacy Device: Philips/Sigmetics S8X305

FEATURES

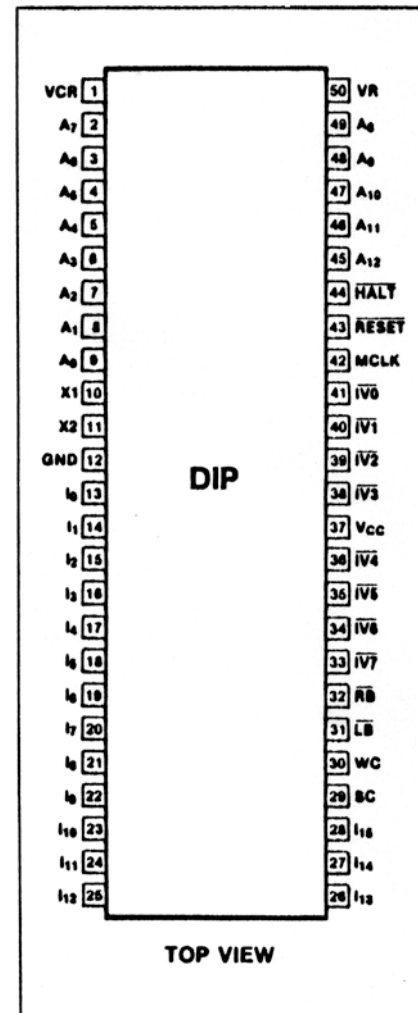
- Fetch, Decode, and Execute a 16-bit Instruction in a minimum of 200ns (one machine cycle)
- Bit-oriented instruction set (addressable single- or multiple-bit subfields)
- Separate buses for instruction, instruction Address and 3-State I/O
- Thirteen 8-bit general-purpose working registers
- Source/destination architecture
- Bipolar low-power Schottky technology/TTL inputs and outputs
- On-chip oscillator and timing generation
- Single +5V supply
- Multiple package options

PRODUCT DESCRIPTION

The Sigmetics 8X305 Microcontroller (Figure 1) is a high-speed bipolar microprocessor implemented with low-power Schottky technology. In a single chip, the 8X305 combines speed, flexibility, and a bit-oriented instruction set. These features and other basic characteristics of the chip combine to provide cost-effective solutions for a broad range of applications. The 8X305 is particularly useful in systems that require high-speed bit manipulations — sophisticated controllers, data communications, very fast interface control, and other applications of a similar nature.

The 8X305 can fetch, decode, and execute a 16-bit instruction word in a minimum of 200ns. Within one instruction cycle, the 8-bit data-processing path can be programmed to rotate, mask, shift, and/or merge single or multiple bit subfields and, in addition, perform an ALU operation; in the same instruction, an external data field can be input, processed, and output to a specified destination — likewise, single or multiple bit data fields can be internally moved from a given source to a given destination. To summarize, fixed or variable-length data fields can be fetched, processed, operated on by the ALU, and moved to a different location — all in a timeframe of 200ns. To interface with I/O and program memory, the 8X305 uses a 13-bit instruction bus, an 8-bit bidirectional multiplexed I/O data/address bus and a 5-bit I/O control bus.

A wide selection of I/O devices, interface chips, and special-purpose parts are available for systems use. In most applications, the more powerful 8X305 is functionally interchangeable with its predecessor — the 8X300.



ABSOLUTE MAXIMUM RATINGS

PARAMETER	DESCRIPTION	RATING	UNIT
V _{CC}	Supply voltage	+7.0	V
X1, X2	Crystal input voltage	2.0	V
All other pins	Logic input pins V _I	5.5	V
T _{STG}	Storage temperature range	-65 to +150	°C

DC ELECTRICAL CHARACTERISTICS 4.5V ≤ V_{CC} ≤ 5.5V, -55°C ≤ T_C ≤ +125°C unless otherwise noted.

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT	COMMENTS
			Min	Typ	Max		
V _{CC}	Supply voltage		4.75	5.0	5.5	V	
V _{IH}	High level input voltage		0.6 2.0		2.0	V	X1 and X2 All other pins
V _{IL}	Low level input voltage				0.4 0.8	V	X1 and X2 All other pins
V _{OH}	High level output voltage	V _{CC} = MIN; I _{OH} = -3mA	2.4			V	
V _{OL}	Low level output voltage	V _{CC} = MIN; I _{OL} = 6mA V _{CC} = MIN; I _{OL} = 16mA			0.55 0.55	V	A ₀ through A ₁₂ All other outputs
V _{CR}	Regulator voltage	V _{CC} = 5V		3.5 3.1 2.6		V	T _A = -55°C T _A = 0°C T _C = 125°C
V _{IK}	Input clamp voltage	V _{CC} = MIN; I _I = -10mA			-1.5	V	Crystal inputs X1 and X2 do not have internal clamp diodes.
I _{IH}	High level input current	V _{CC} = MAX V _{IH} = 0.6V V _{IH} = 4.5V			4.0 50	mA μA	X1 and X2 All other pins
I _{IL}	Low-level input current	V _{CC} = MAX; V _{IL} = 0.4V			-3 -0.3 -1.6 -0.4	mA	X1 and X2 IV0 - IV7 I0 - I15 HALT and RESET
I _{OS}	Short circuit output current	V _{CC} = MAX; (Note: At any time, no more than one output should be connected to ground.)	-30		-140	mA	All output pins
I _{CC}	Supply current	V _{CC} = MAX			175 205	mA	T _C = 125°C T _A = -55°C
I _{REG}	Regulator control	V _{CC} = 5.0V	-10		-25	mA	Max available base drive for series-pass transistor
I _{CR}	Regulator current	V _{CC} = MAX			180 260	mA	T _C = 125°C T _A = -55°C

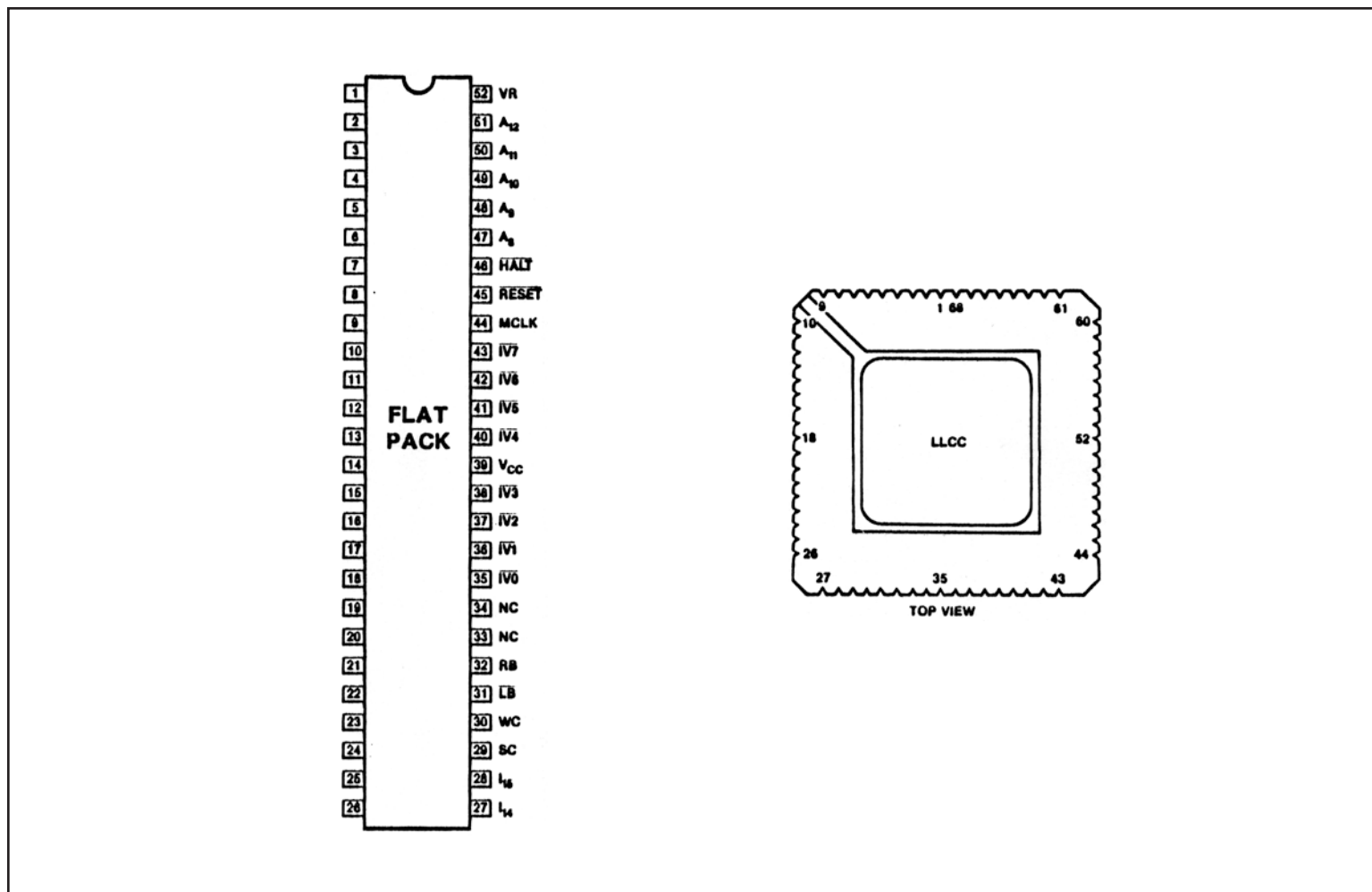
NOTES:

- Operating temperature ranges are guaranteed after thermal equilibrium has been reached.
- All voltages measured with respect to ground terminal.

AC ELECTRICAL CHARACTERISTICS CONDITIONS: $4.5V < V_{CC} < 5.5V$; $-55^{\circ}C < T_C < 125^{\circ}C$
 LOADING: (See test circuits)

SYMBOL	PARAMETER (NOTE 1)	LIMITS (INSTRUCTION CYCLE TIME = 200ns)			LIMITS (INSTRUCTION CYCLE TIME > 200ns)			UN-ITS	COMMENTS
		Min	Typ	Max	Min	Typ	Max		
T_{PC}	Processor cycle time	200			200			ns	
T_{CP}	X1 clock period	100			100			ns	
T_{CH}	X1 clock high time	50			50			ns	
T_{CL}	X1 clock low time	50			50			ns	
T_{MCL}	MCLK low delay	15		40	15		40	ns	
T_W	MCLK pulse width	30		60	$T_{4Q} - 10$		$T_{4Q} + 10$	ns	Note 2
T_{MODO}	Output driver turn on time MCLK falling edge	125		148	$T_{1Q} +$ $T_{2Q} + 25$		$T_{1Q} +$ $T_{2Q} + 45$	ns	Note 9
T_{DI}	Output driver turn-on time (SC/WC rising edge)	20			20			ns	Note 10
T_{DD}	Input data to output data	75		105	75		105	ns	
T_{MHS}	MCLK falling edge to \overline{HALT} falling edge			30			$T_{1Q} - 20$	ns	Note 2
T_{MHH}	\overline{HALT} hold time (MCLK falling edge)	65			$T_{1Q} + 15$			ns	Note 2
T_{ACC}	Program storage access time			60				ns	Note 12
T_{IO}	I/O port output enable time ($\overline{LR}/\overline{RB}$ to valide \overline{IV} data input)			20				ns	
T_{MAS}	MCLK falling edge to address stable			140			$T_{1Q} +$ $T_{2Q} + 40$	ns	Notes 2, 3, & 4
T_{IA}	Instruction to address			140			$T_{2Q} + 90$	ns	Notes 2, 3 & 5
T_{IVA}	Input data to address			95			85	ns	Notes 3 & 6
T_{MIS}	MCLK falling edge to instruction stable			25			$T_{1Q} - 20$	ns	Notes 2 & 10
T_{MIH}	Instruction hold time (MCLK falling edge)	55			$T_{1Q} + 5$			ns	Notes 2 & 8
T_{MWH}	MCLK falling edge to SC/WC rising edge	100		128	$T_{1Q} +$ $T_{2Q} + 5$		$T_{1Q} +$ $T_{2Q} + 25$	ns	Notes 2 & 11
T_{MWL}	MCLK falling edge to SC/WC falling edge	0		15	0		15	ns	
T_{MIBS}	MCLK falling edge to $\overline{LB}/\overline{RB}$ (Input phase)	8		25	8		25	ns	
T_{IIBS}	Instruction to $\overline{LB}/\overline{RB}$ (Input phase)			25			25	ns	
T_{MOBS}	MCLK falling edge to $\overline{LB}/\overline{RB}$ (Output phase)	115		145	$T_{1Q} +$ $T_{2Q} + 15$		$T_{1Q} +$ $T_{2Q} + 45$	ns	Note 2
T_{MIDS}	MCLK falling edge to input data stable			55			$T_{1Q} +$ $T_{2Q} - 45$	ns	Note 2
T_{MIDH}	Input data hold time (MCLK falling edge)	115			$T_{1Q} +$ $T_{2Q} + 15$			ns	Notes 2 & 11

PIN CONFIGURATIONS (Continued)



PIN DESCRIPTION

FLATPACK	LLCC	DIP	IDENTIFIER	FUNCTION
PIN NO.	PIN NO.	PIN NO.		
1	1, 68	1	VCR	Regulated voltage input from series-pass transistor (2N5320 or equivalent).
2-9, 47-51	4-11, 62-66	2-9, 45-49	A ₀ - A ₁₂	Program Address Lines: These active-high outputs permit direct addressing of up to 8192 words of program storage; A ₁₂ is least significant bit.
10-11	12, 13	10, 11	X1, X2	Timing generator connections for a capacitor, a series resonant crystal, or an external clock source with complementary outputs.
12	2,3, 14-16	12	GND	Ground.
13-28	17-23, 28-36	13-28	I ₀ - I ₁₅	Instruction Lines: These active-high input lines receive 16-bit instructions from program storage; I ₁₅ is least significant bit.
29	37	29	SC	Select Command: When high (binary 1), an address is being output on pins $\overline{IV0}$ through $\overline{IV7}$.
31	38	30	WC	Write Command: When high (binary 1), data is being output on pins $\overline{IV0}$ through $\overline{IV7}$.

PIN DESCRIPTION (Continued)

FLATPACK	LLCC	DIP	IDENTIFIER	FUNCTION
PIN NO.	PIN NO.	PIN NO.		
31	39	31	\overline{LB}	Left Bank Control: When low (binary 0), devices connected to the Left Bank are accessed. (Note. Typically, the \overline{LB} signal is tied to the \overline{ME} input pin of I/O peripherals).
32	45	32	RB	Right Bank Control: When low (binary 0), devices connected to the Right Bank are accessed (Note. Typically, the \overline{RB} signal is tied to the \overline{ME} input pin of I/O peripherals).
35-38, 40-43	46-49, 55-58	33-36, 38-41	$\overline{IV0} - \overline{IV7}$	Interface Vector (Input/Output Bus) — these bidirectional active-low three-state lines communicate data and/or addresses to I/O devices and memory locations. A low voltage level equals a binary "1"; $\overline{IV7}$ is Least Significant Bit.
39	50-52	37	V _{CC}	+5V power supply.
44	59	42	MCLK	Master Clock: This active-high output signal is used for clocking I/O devices and/or synchronization of external logic.
45	60	43	RESET	When RESET input is low (binary 0), the 8X305 is initialized — sets Program Counter/Address Register to zero and inhibits MCLK. For the period of time RESET is low, the Left Bank/Right Bank ($\overline{LB}/\overline{RB}$) signals are forced high asynchronously.
46	61	44	HALT	When HALT input is low (binary 0), internal operation of the 8X305 stops at the start of next instruction; MCLK is not inhibited nor is any internal register affected; however, both the Left Bank/Right Bank ($\overline{LB}/\overline{RB}$) signals are synchronously driven high during the first quarter of the instruction cycle time and remain high during the time HALT is low.
52	67	50	VR	Internally-generated reference output voltage for external series-pass regulator transistor.
33, 34	24-27, 40-44, 53, 54	-	No Connect	

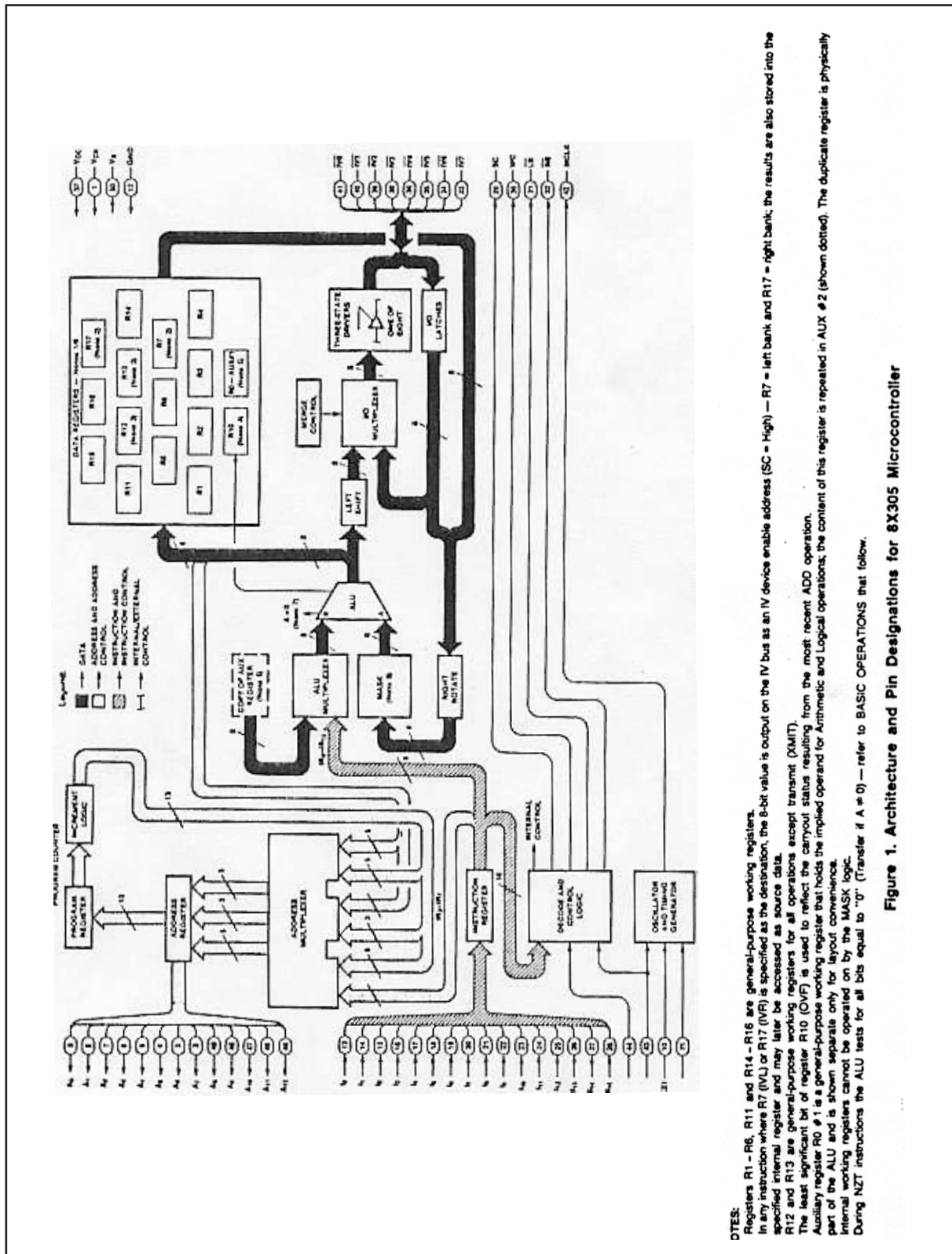


Figure 1. Architecture and Pin Designations for 8X305 Microcontroller

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